

<p>Substitute for form 1449A/PTO</p> <p>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</p> <p>(Use as many sheets as necessary)</p>	<i>Complete if Known</i>	
	Application Number	10/612,793
	Filing Date	July 2, 2003
	First Named Inventor	Arup Bhattacharyya
	Group Art Unit	2826
	Examiner Name	Thomas Dickey
Sheet 1 of 1	Attorney Docket No: 1303.111US1	

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Examiner Initials*	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ¹
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EXAMINER

DATE CONSIDERED